

IN THE SPECIFICATION

Please amend the specification at page 1, lines 3-8, as follows:

Cross Reference to Related Applications

This application is related to an application by Luk et al., entitled 3T1D MEMORY CELLS USING GATED DIODES AND METHODS OF USE THEREOF, U.S. Patent Serial No. ~~XX/XXX,XXX~~ 10/751,713, filed on the same day as the present application and assigned to International Business Machines, Inc., the disclosure of which is hereby incorporated by reference.